

Data sheet acquired from Harris Semiconductor SCHS015

# **CMOS NOR Gates**

High-Voltage Types (20-Volt Rating)

Quad 2 Input — CD4001B Dual 4 Input — CD4002B Triple 3 Input — CD4025B

■ CD4001B, CD4002B, and CD4025B NOR gates provide the system designer with direct implementation of the NOR function and supplement the existing family of CMOS gates. All inputs and outputs are buffered.

The CD4001B, CD4002B, and CD4025B types are supplied in 14-lead hermetic dual-in-line ceramic packages (D and F suffixes), 14-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

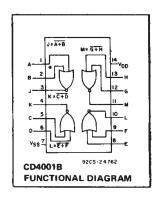
# CD4001B, CD4002B, CD4025B Types

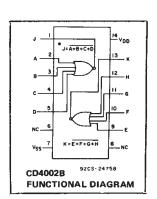
### Features:

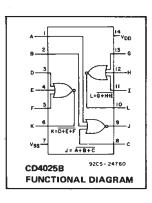
- Propagation delay time = 60 ns (typ.) at C<sub>L</sub> = 50 pF, V<sub>DD</sub> = 10 V
- Buffered inputs and outputs
- Standardized symmetrical output characteristics
- 100% tested for maximum quiescent current at 20 V
- 5-V, 10-V, and 15-V parametric ratings
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package temperature range):

1 V at V<sub>DD</sub> = 5 V 2 V at V<sub>DD</sub> = 10 V 2.5 V at V<sub>DD</sub> = 15 V

 Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of "B" Series CMOS Devices"







### STATIC ELECTRICAL CHARACTERISTICS

CHARACTER- ISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							
	Vo	VIN	VDD						+25		UNITS
	(V)	(V)	(V)	-55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent Device Current, IDD Max.		0,5	5	0.25	0.25	7.5	7.5	_	0.01	0.25	μΑ
		0,10	10	0.5	0.5	15	15	-	0.01	0.5	
	_	0,15	15	1	1	30	30		0.01	1	
	_	0,20	20	5	5	150	.150	_	0.02	5	
Output Low (Sink) Current IQL Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	-	
	1.5	0,15	15	4.2	4	2.8	2.4	34	6.8	_	
Output High (Source) Current, IOH Min.	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mA
	2,5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	3.2	-	
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	_	
Output Voltage: Low-Level, VOL Max.		0,5	5	0.05			-	0	0.05	V	
	_	0,10	10	0.05			-	0	0.05		
		0,15	15	0.05			-	0	0.05		
Output Voltage: High-Level, VOH Min.		0,5	5	4.95			4.95	5			
	_	0,10	10	9.95			9.95	10	-		
	-	0,15	15	14.95			14.95	15	-		
Input Low Voltage, VIL Max.	0.5,4.5	_	5	1.5			_	_	1.5		
	1,9	_	10	3					3	V	
	1.5,13.5	-	15	4			-	_	4		
Input High Voltage, VIH Min.	0.5	-	5	3.5			3.5	_	_		
	.1		10	7			7		-		
	1.5	-	15	11			11		]		
Input Current IIN Max.		0,18	18	±0.1	±0.1	±1	±1	_	±10~5	±0.1	μА

## CD4001B, CD4002B, CD4025B Types

### **RECOMMENDED OPERATING CONDITIONS**

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIM		
CHARACTERISTIC	MIN.	MAX.	UNITS
Supply-Voltage Range (For T <sub>A</sub> = Full Package Temperature Range)	3	18	٧

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### **DYNAMIC ELECTRICAL CHARACTERISTICS**

At  $T_A = 25^{\circ}C$ ; Input  $t_f$ ,  $t_f = 20$  ns,  $C_L = 50$  pF,  $R_L = 200k\Omega$ 

CHARACTERISTIC	TEST CONDITIONS		ALL 1	UNITS	
		V <sub>DD</sub> VOLTS	TYP.	MAX.	
Propagation Delay Time,		5	125	250	
tPHL, tPLH		10	60	120	ns
		15	45	90	
		5	100	200	
Transition Time,		10	50	100	ns
tthe, tteh		15	40	80	
Input Capacitance, C <sub>IN</sub>	Any Input		5	7.5	pF

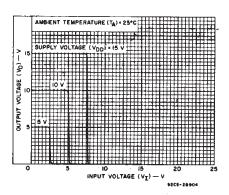


Fig. 1 - Typical voltage transfer characteristics.

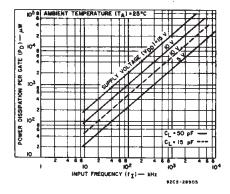


Fig.2 - Typical power dissipation vs. frequency.

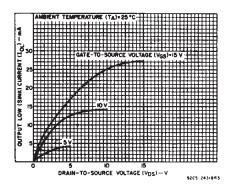


Fig.3 – Typical output low (sink) current characteristics.

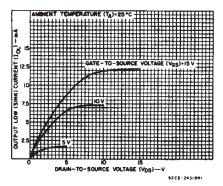


Fig. 4 - Minimum output low (sink) current characteristics.

# CD4001B, CD4002B, CD4025B Types

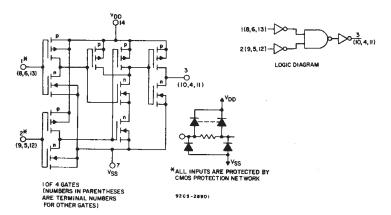


Fig.5 - Schematic and logic diagrams for CD4001B.

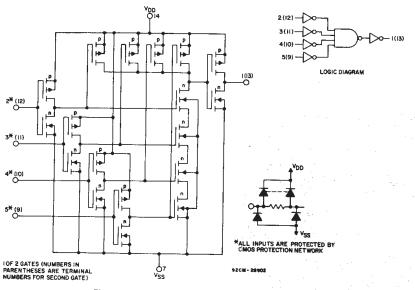


Fig. 6 - Schematic and logic diagrams for CD4002B.

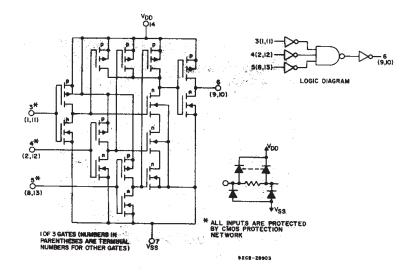


Fig. 7 - Schematic and logic diagrams for CD4025B.

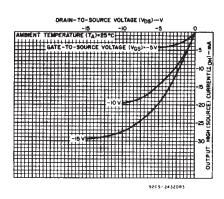


Fig. 8 - Typical output high (source) current characteristics.

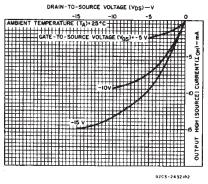


Fig. 9 - Minimum output high (source) current characteristics.

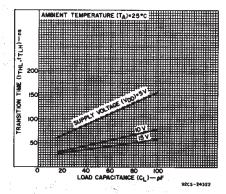


Fig. 10 - Typical transition time vs. load capacitance.

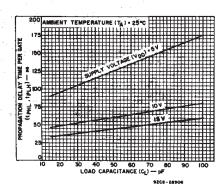
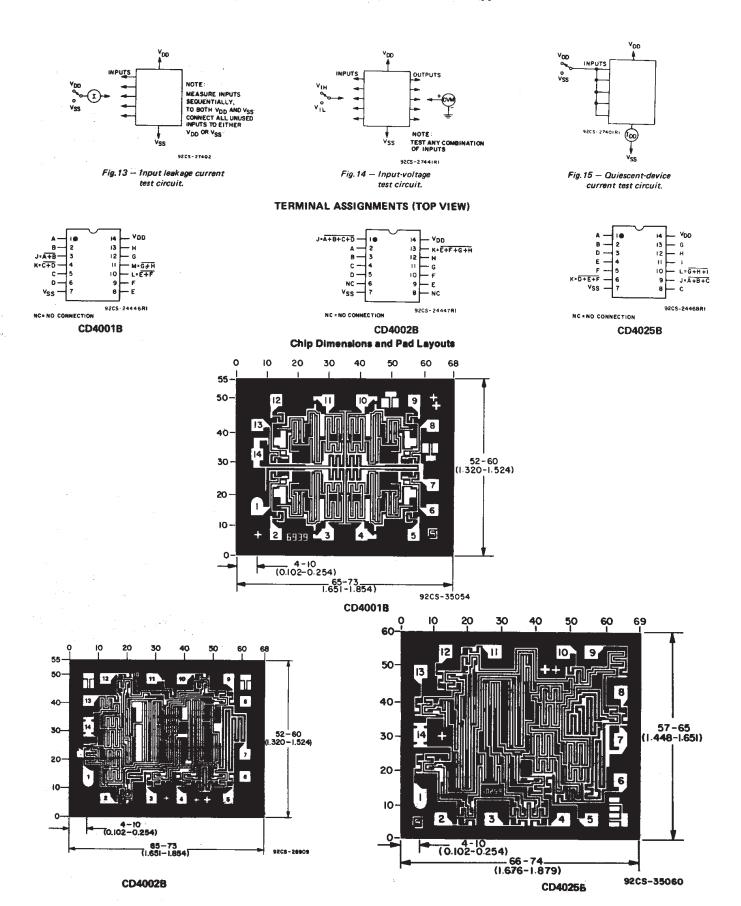


Fig. 11 - Typical propagation delay time vs. load capacitance.

## CD4001B, CD4002B, CD4025B Types



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